

DONGGUAN ZHONGGUI ELECTRONICS CO., LTD

Digital Transistors (Built-in Resistors)

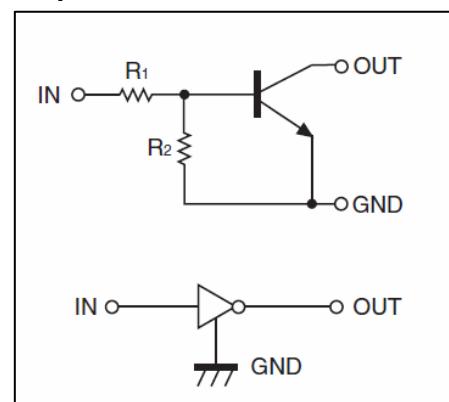
DTC123EM/DTC123EE/DTC123EUA DTC123EKA /DTC123ECA/DTC123ESA

DIGITAL TRANSISTOR (NPN)

FEATURES

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy

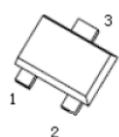
• Equivalent Circuit



PIN CONNECTIONS and MARKING

DTC123EM

SOT -723

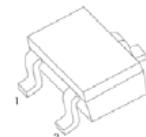


1. IN
2. GND
3. OUT

MARKING: 22

DTC123EE

SOT -523

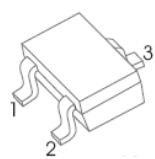


1. IN
2. GND
3. OUT

MARKING: 22

DTC123EUA

SOT -323

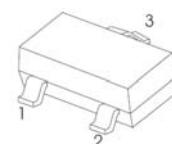


1. IN
2. GND
3. OUT

MARKING: 22

DTC123E KA

SOT -23-3L

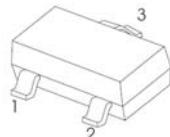


1. IN
2. GND
3. OUT

MARKING: 22

DTC123ECA

SOT -23



1. IN
2. GND
3. OUT

MARKING: 22

DTC123ESA

T O-92S



1. GND
2. OUT
3. IN

MAXIMUM RATINGS(Ta=25°C unless otherwise noted)

Symbol	Parameter	Limits(DTC123E□)						Unit
		M	E	UA	KA	CA	SA	
V _{cc}	Supply Voltage			50				V
V _{IN}	Input Voltage			-10~+12				V
I _O	Output Current			100				mA
P _D	Power Dissipation	100	150	200	200	200	300	mW
T _j	Junction Temperature			150				°C
T _{stg}	Storage Temperature			-55~+150				°C

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input voltage	V _{I(off)}	V _{CC} =5V,I _O =100μA	0.5			V
	V _{I(on)}	V _O =0.3V,I _O =20mA			3	V
Output voltage	V _{O(on)}	I _O /I _I =10mA/0.5mA			0.3	V
Input current	I _I	V _I =5V			3.8	mA
Output current	I _{O(off)}	V _{CC} =50V,V _I =0			0.5	μA
DC current gain	G _I	V _O =5V,I _O =20mA	20			
Input resistance	R ₁		1.54	2.2	2.86	kΩ
Resistance ratio	R _{2/R₁}		0.8	1	1.2	
Transition frequency	f _T	V _O =10V,I _O =5mA,f=100MHz		250		MHz